

*(Use several sheets if necessary)*

**BUR920010011US1(1-1)**

## Unassigned

Jeffrey B. Johnson, et al.

**Herewith**

## Unassigned

[illegible]

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2F		Palestri, P., et al., "A Better Insight into the Performance of Silicon BJT's Featuring Highly Nonuniform Collector Doping Profiles," IEEE Transactions On Electron Devices, Vol. 47, No. 5, May 2000, pp. 1044-1051;
0F		van Noort, W.D., et al., "Reduction of UHF Power Transistor Distortion with a Non-Uniform Collector Doping Profile," IEEE BCTM 7.2, (2000), pp. 126-129

Don Shi

2-19-02

**Form PTO-A820**  
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